Lecture 15 Nonvolatile Memory & Energy Management

CE346 – Microprocessor System Design Branden Ghena – Fall 2023

Some slides borrowed from: Josiah Hester (Northwestern), Prabal Dutta (UC Berkeley)

Northwestern

Administrivia

- Quiz today! Remind me at 4:30
- Office Hours
 - Still available for projects
 - Friday 1-5 we'll be in the Ford classroom for project help
- Projects
 - Get working on them! Likely can't order new things after Thanksgiving
- Hardware
 - I have *the rest* of the hardware on hand to distribute
 - Let's do it right now so I don't have to interrupt the quizzes later

Bonus Topics

• We won't have time to talk about these, but I have slides, so I included them at the end of this lecture

• SD Card protocol

• PPI and task/event chaining

Today's Goals

- Discuss uses of memory, especially nonvolatile memory, in embedded systems
- Introduce internal flash peripheral

- Discuss matters of energy on embedded systems
 - Where to gain energy?
 - How much does the Microbit use?
 - How do we write software for *very* low energy systems?

Outline

Memory in Computing

• nRF52 Non-Volatile Memory Controller

- Energy Sources
- Microbit Energy Use
- Intermittent Computing

Memory in computing

• Various different memories serve different purposes in computing

- Needs
 - Fast, infinite-lifetime memory to keep things like stack memory
 - Nonvolatile memory that can be read from
- Desires
 - Fast, infinite-lifetime nonvolatile memory

Register technology: SRAM

- Static RAM (SRAM)
 - Each cell stores a bit in a bi-stable circuit, typically a six-transistor circuit
 - Static no need for periodic refreshing; keeps data while powered



- Relatively insensitive to disturbances such as electrical noise
 - Energetic particles (alpha particles, cosmic rays) can flip stored bits
- Fastest memory on computer
 - Also most expensive and takes up most space per bit
 - Typically used for registers and cache memories

SRAM can be used a permanent memory in a pinch

• Gameboy and Gameboy Color used batteries to save state

 Gameboy Advanced games used batteries for an internal clock

• PSA: old Gameboy games have likely lost their save files



Disk drive storage





Shock resistant up to 55g (operating) Shock resistant up to 350g (non-operating)



Shock resistant up to 1500g (operating and non-operating)

Necessity breeds creativity

 Original iPod used a small disk drive





Floating-gate transistors

- Concept behind transistor-based non-volatile memory
 - EPROM, EEPROM, and Flash
 - High voltage on control gate creates charge on floating gate
 - Charge on floating gate activates/deactivates transistor



EPROM

- Erasable programmable read-only memory
- Erasable
 - If you shine UV light directly on the IC
 - Needed a window to expose the IC
- Programmable
 - With high voltage (25-50 volts)
- Typically acted as read-only memory in circuits



EEPROM

- Electrically-erasable programable read-only memory
- Same concept as EPROM, but includes internal circuitry to allow rewriting under normal conditions
 - Slow and high-power to write
 - Has a longer lifetime compared to flash, ~100k writes
- Can be built into other ICs
 - Example: AT90USB162 microcontroller (512 bytes)





Flash

- Similarly based on floating-gate transistors
 - But with a different design that allows for faster erase of entire blocks
 - More limited lifetime, ~1k-100k writes (10k common for embedded)
- Cannot erase individual bytes, must erase in units of blocks
 - Read can happen in units of bytes though
- Heavily used in commercial devices
 - Flash drives
 - SSDs
 - Smartphone storage
 - Microcontroller non-volatile storage!

More exotic memories

- FRAM and MRAM are both rising protentional Flash replacements
 - Non-volatile
 - Writable at the byte level
 - Very high to infinite write/erase cycles
 - Lower energy costs for writing and reading
- They use unrelated magnetic techniques for data storage
- Starting to appear in microcontrollers
 - TI MSP430s have used 16 kB FRAM
 - Apollo4 (ARM Cortex-M4F) has 2 MB of MRAM

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Flash memory on the nRF52833

- 512 kB total Flash memory
 - 128 pages each 4 kB in size
- Non-Volatile Memory Controller (NVMC) controls access
 - Enables writing to flash
 - Enables erasing flash
 - Manages status of flash



Writing to Flash

- Configurable, disabled by default
 - Enable with configuration register
- Rules for writing to Flash
 - Must write word-aligned 32-bit values
 - Can only write 0 values, not ones
 - Can only write 2 times before erasing (even if there are still 1 bits)

- Takes 42.5 μs to write a 32-bit word
 - 64 MHz clock ⇒ 2720 cycles per 32-bit write

Erasing Flash

- Lifetime: 10000 erase cycles per page
- Options
 - Erase a single page (4 kB): 87.5 ms
 - Erase all of flash (512 kB): 173 ms
- CPU is halted if executing code from Flash during the erase
 - That's 5.6 million cycles...
 - Code can execute from SRAM instead
 - Can also be split into a series of partial erases
 - Which must add up to a complete erase time before writing

Factory Information Configuration Registers

- Read-only memory
- Chip-specific information and configuration
 - Code size
 - Unique device ID
 - Production IDs
 - Temperature conversion functions

User Information Configuration Registers

- Additional Flash memory for non-volatile user configurations
 - Writable and erasable through NVMC processes described earlier
- 32 words of customer information (128 bytes total)
- Special configurations
 - Reset pin
 - NFC pin enable/disable
 - Debug configuration

Break + Question

• Could you run a system entirely within Flash?

• Could you run a system entirely within RAM?

Break + Question

- Could you run a system entirely within Flash?
 - Yes, but it would go _very_ slowly
 - Local variables would be pretty hard to manage
 - 87.5 ms of code pause every time you write to a variable...

- Could you run a system entirely within RAM?
 - Yes, but code would need to be loaded from somewhere else
 - Need initial state that is nonvolatile
 - Would run just as fast and be lower energy, actually

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Measuring energy use

- Base equations
 - Power = Current * Voltage (Watts)
 - Energy = Power * Time (Joules)
- Energy = volts * amps * seconds
 - Voltage is *usually* constant for a system
 - Time is how long you are running for / measurement period
 - Current changes based on activities being done
 - Often energy is presented as a current draw
 - Maybe an average current draw
 - With Voltage and Time implicit

Example current trace during wireless communication



Current Consumption versus Time during a single Connection Event

Wired power through USB

- Provides 5v at up to 500 mA (USB 2.0) or 900 mA (USB 3.0)
 - Or power delivery specifications, which can do far more power
- Must be converted to different voltage to use
 - Voltage regulator takes in 5v and spits out 3.3v
 - Has its own maximum current!
- System is limited by the minimum of USB or regulator power
 - Microbit: regulator gives 3.3v at up to 600 mA
 - USB 2.5 Watts, Regulator 1.98 Watts ⇒ System 1.98 Watts
 - This is a max! Stay 15-30% below regulator limit

Thinking about energy

- Batteries often list energy in mA*h (milliamp hours)
 - Coin cell battery: 3v at 220 mAh
 - 2x AA battery: 3v at 2000 mAh
 - iPhone 11 battery: 3.7v at 3000 mAh
- Also usually limited by regulator
 - Sometimes just directly connected to system
 - We can run at 3v just fine! (3.7v is no good though)
- Voltage can vary with charge
 - But only a little, right before battery is depleted
 - Example: coin cell goes down to ~2.7 volts





How are batteries measured?

- Measuring energy remaining is a difficult problem
 - Many questions to be handled
 - How much did it start with?
 - How much energy has been used?
 - What type of battery is it?
 - Energy is not as constant a quantity as one would hope
 - Pulling out lots at once has an overhead penalty
- Coulomb Counter (aka Battery Fuel Gauge)
 - Designed for a specific battery "chemistry"
 - Monitors charge flowing in each direction
 - I2C interface for reading battery state
- Accuracy is not exact, more of an educated guess



How are batteries managed?

- Usually a dedicated IC for charging and managing battery packs
 - Recharges battery with appropriate amount of current
 - Monitors issues of battery health
 - Various status monitoring
 - Overcharge, undercharge
 - Overcurrent
 - Overtemperature, undertemperature
 - Will go so far as to cut off the system to protect the battery
- Takeaway: complicated problem, approach with caution!
 - Best to reuse an existing design, if possible

Microbit only uses battery energy in a simple way

- Battery input connects directly to regulator
 - No protection for battery health
 - No battery charging capabilities
- Usually this is fine for simple, low-power systems
 - It means that the input voltage can vary though
 - Makes the reference voltages for the ADC/Comparator more important

Energy harvesting

- Grab energy from the environment and use that!
 - Could augment with a battery and use energy to recharge
 - Could go entirely batteryless and live on harvested energy alone

Sources

- Light (outdoor or indoor. most successful)
- Airflow (outdoor or air vents)
- Motion (on human body)
- Temperature differential (difficult in practice)
- RF (very low energy source)

Temperature harvesting from hot pipes

- Peltier junctions create a voltage from temperature differential
 - Challenge: needs a large differential for more energy





Managing harvested energy

- Often uses an IC to pull in energy and provide to system
- Harvested voltage/current are often very small
 - Signal in millivolts is pretty common
 - Need to accumulate over time to power system
 - Fill up a capacitor
- Need particular load for maximum power
 - ICs often implement Maximum Power Point Tracking (MPPT)
 - Varies load automatically to always harvest the most possible energy



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Thinking about energy

- Battery energy
 - Coin cell battery: 3v at 220 mAh
 - 2x AA battery: 3v at 2000 mAh
 - iPhone 11 battery: 3.7v at 3000 mAh
- nRF52833 active current: 5.6 mA (at 3v)
 - Coin cell: 40 hours -> ~2 days
 - 2x AA: 360 hours -> ~15 days
 - iPhone 11: 535 hours -> ~22 days
- So how does any of this work???





Sleep mode power draw



Microcontroller sleep modes

- Sleep mode
 - Processor stops running but memory values are preserved
 - Most peripherals are disabled
 - Continues until an interrupt occurs and wakes the microcontroller
 - Usually a timer or GPIO input
- nRF52833 sleep mode current: 1.8 µA (GPIO port event only)
 - Coin cell: 122222 hours -> ~5000 days -> ~14 years
- Low-power systems shoot for less than 1% duty cycle
 - Average current of ${\sim}100~\mu\text{A}$ or less
 - Warning: other stuff on the board counts!!
 - LEDs are 1-10 mA each... Power is not a concern of the Microbit

Microbit current draw (microcontroller)

- Active CPU
 - 5.6 mA (executing from Flash)
 - 1.8 μ A (sleep mode with RAM retention)
- Transmitting RF packet
 - 15.5 mA (+8 dBm)
- Other peripherals
 - SAADC: 1.37 mA
 - Timer: 729 µA (for any Timer peripheral)
 - I2C: 6.6 mA (pull-down resistors when transmitting 0 bit)
 - Everything else is handfuls of μA

Microbit current draw (non-microcontroller)

- KL27 (JTAG interface microcontroller)
 - 2 µA sleep, 8 mA active
- Speaker
 - 0-27.5 mA (changes with input signal)
- Microphone
 - 0-120 μ A (activated with GPIO pin)
- Accelerometer/Magnetometer
 - 2-212 μ A (depends on sensing rates, 200 is magnetometer)
- LEDs
 - 0-230 mA (can be activated individually)
- Everything else
 - 0-1 mA (mostly due to pull-up resistors)

Max and min current for Microbit

- Maximum current: 280 mA at 3.3 volts (~1 W)
 - With *everything* active
 - Well within limits of regulator
- Minimum current
 - \sim 15 mA (always-on power LED)
 - If you removed the power LED:
 - <100 μ A (with everything off)

nRF52 sleep mode

- Triggered with assembly instruction
 - WFI (Wait For Interrupt) or WFE (Wait For Event)
- Stops processor until woken by interrupt, exception, or event
- On nRF52 automatically disables high frequency clock if unneeded

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Reducing energy consumption even further

- If sleep isn't enough, you can power things off completely
 - Transistor can be used to turn off the sensor



Energy harvesting can lead to intermittent computing





Disabling the microcontroller

- Even 2 μ A sleep current might be too much for energy harvesting
 - Can turn off microcontroller periodically
 - Enable it again once VCC returns
- Problem: how do you write software to deal with intermittency?
 - Run-to-completion with relatively quick code
 - Initialize, sample sensor, send packet, turn off again
 - Code checkpointing
 - Save state from code and restore when power resumes
 - Might be as little as which state the system is in, plus some samples
 - Might be as much as saving entire stack state
 - Needs low-energy, nonvolatile storage (FRAM or MRAM help!)

Programs may not finish





Execution Time

Programs may not finish



Programs may not finish



Checkpointing enables progress



Checkpointing enables progress



Checkpointing enables progress



Checkpointing goals

- Have the compiler automatically insert checkpoints as needed
 - Human doesn't have to think about them when programming
- Limit checkpointing overhead while maximizing forward progress
 - Checkpointing will take time to perform, so want to do it rarely
 - Rarer checkpoints mean more progress is lost in average outage
 - Need to compromise on the two based on available energy

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Outline

Bonus: SD Cards

SD card references

- ChaN
 - Embedded systems engineer in Japan (and is amazing)
 - <u>http://elm-chan.org/docs/mmc/mmc_e.html</u>
 - <u>http://elm-chan.org/fsw/ff/00index_e.html</u>

- Various others
 - <u>http://users.ece.utexas.edu/~gerstl/ee445m_s15/lectures/Lec08.pdf</u>
 - <u>http://alumni.cs.ucr.edu/~amitra/sdcard/Additional/sdcard_appnote_foust.pdf</u>
 - <u>https://luckyresistor.me/cat-protector/software/sdcard-2/</u>
 - <u>http://users.ece.utexas.edu/~valvano/EE345M/SD_Physical_Layer_Spec.pdf</u>
 - <u>https://github.com/tock/tock/blob/master/capsules/src/sdcard.rs</u>

SD cards

- "Secure Digital" Card
 - Includes various formfactors
 - Flash memory
 - Capacities from 8 MB to 128 TB
 - 512 byte blocks
- Supports 1-bit SPI interface
 - As well as 4-bit SD bus protocol
- Easy to support in embedded systems
 - Cheap but high power



Electrical connections for an SD card

- SD Card connections
 - SPI SDI, SDO, CS, SCLK
 - Plus a switch to enable/disable the SD card and a detect signal



Controlling the SD card

- Index: 6-bit value of command being sent
- Argument: 32-bit value that may be arguments to commands
- CRC: checks for bit errors
- Response (after delay)



SD card SPI commands

| Command Index | Argument | Response | Data | Abbreviation | Description | | | | |
|---------------|---------------------------|----------|------|--------------------------|---|--|--|--|--|
| CMD0 | None(0) | R1 | No | GO_IDLE_STATE | Software reset. | | | | |
| CMD1 | None(0) | R1 | No | SEND_OP_COND | Initiate initialization process. | | | | |
| ACMD41(*1) | *2 | R1 | No | APP_SEND_OP_COND | For only SDC. Initiate initialization process. | | | | |
| CMD8 | *3 | R7 | No | SEND_IF_COND | For only SDC V2. Check voltage range. | | | | |
| CMD9 | None(0) | R1 | Yes | SEND_CSD | Read CSD register. | | | | |
| CMD10 | None(0) | R1 | Yes | SEND_CID | Read CID register. | | | | |
| CMD12 | None(0) | R1b | No | STOP_TRANSMISSION | Stop to read data. | | | | |
| CMD16 | Block length[31:0] | R1 | No | SET_BLOCKLEN | Change R/W block size. | | | | |
| CMD17 | Address[31:0] | R1 | Yes | READ_SINGLE_BLOCK | Read a block. | | | | |
| CMD18 | Address[31:0] | R1 | Yes | READ_MULTIPLE_BLOCK | Read multiple blocks. | | | | |
| CMD23 | Number of blocks[15:0] | R1 | No | SET_BLOCK_COUNT | For only MMC. Define number of blocks to transfer with next multi-block read/write command. | | | | |
| ACMD23(*1) | Number of blocks[22:0] | R1 | No | SET_WR_BLOCK_ERASE_COUNT | For only SDC. Define number of blocks to pre-erase with next multi-block write command. | | | | |
| CMD24 | Address[31:0] | R1 | Yes | WRITE_BLOCK | Write a block. | | | | |
| CMD25 | Address[31:0] | R1 | Yes | WRITE_MULTIPLE_BLOCK | Write multiple blocks. | | | | |
| CMD55(*1) | None(0) | R1 | No | APP_CMD | Leading command of ACMD <n> command.</n> | | | | |
| CMD58 | None(0) | R3 | No | READ_OCR | Read Operations Condition Register (OCR). Indicates supported working voltage range. | | | | |

Reading from the SD card

Single block read



• Multiple block read (CMD12 – Stop Transmission)



SD card delays can be significant

- Performing a single byte read
 - Almost 300 µs before the SD card starts sending data
 - \sim 200 µs additional time to send the 512 bytes (20 Mbps data, 8 Mbps total)



| USBee SX Logic Analyzer | | | | | | | | | | | | | | | | | |
|-------------------------|------|------|---|------|---|---|---|---|--------|--------|---------|---------|---------|---------|---------|-------|----|
| File | View | Setu | p | Help | | | | | | | | | | | | | |
| | | _ | 1 | 2 | 3 | 4 | 1 | 16.5us | 50.5us | 84.5us | 118.5us | 152.5us | 186.5us | 220.5us | 254.5us | 288.5 | us |
| P/ | 44 S | S | = | = | Ξ | = | | , i i i i i i i i i i i i i i i i i i i | | | | | | | | Ű | |
| N | 105 | 1 | | = | = | | | 1 | | | | | | | | | |
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| F | PB1 | 5, | _ | - | | - | | | | | | | | | | | |

Writing to the SD card

• Single block write



• Multiple block write



Layering a filesystem on top of an SD card

• FatFs library implements the filesystem agnostic of application and storage medium

- Enables the use of file system calls:
 - Open, Close, Read, Seek
- Connects to generic interface for low-level implementation
 - disk_status, disk_init, disk_read, disk_write



Outline

• Bonus: Task/Event Chaining with PPI

Software stops when the processor does, but peripherals continue

• Problem: when the processor is off, no code is running

- Solutions
 - Peripherals can wake it up again
 - Can probably go for milliseconds to minutes without any actions
 - Timer interrupt can wake processor to do things
 - Have hardware handle some parts in the background without the processor's involvement
 - DMA
 - PPI

Controlling peripherals while processor sleeps

- DMA (Direct Memory Access)
 - Set up a pointer to memory and a length
 - Peripheral can load/store memory without processor's involvement
 - Usually use completion interrupt to wake processor
- PPI (Programmable Peripheral Interconnect)
 - Any Event can be tied to any Task within the nRF52
 - Allows for complicated actions to be chained together

nRF52 Tasks and Events

- Tasks are used to perform some operation
 - Often written to by software
- Events change value when some change in status occurs
 - Often used to trigger interrupts
- PPI peripheral can connect any TASK to any EVENT

Example: Timer peripheral

| Register | Offset | Description |
|-------------------|--------|---------------------------------------|
| TASKS_START | 0x000 | Start Timer |
| TASKS_STOP | 0x004 | Stop Timer |
| TASKS_COUNT | 0x008 | Increment Timer (Counter mode only) |
| TASKS_CLEAR | 0x00C | Clear time |
| TASKS_SHUTDOWN | 0x010 | Shut down timer |
| TASKS_CAPTURE[0] | 0x040 | Capture Timer value to CC[0] register |
| TASKS_CAPTURE[1] | 0x044 | Capture Timer value to CC[1] register |
| TASKS_CAPTURE[2] | 0x048 | Capture Timer value to CC[2] register |
| TASKS_CAPTURE[3] | 0x04C | Capture Timer value to CC[3] register |
| TASKS_CAPTURE[4] | 0x050 | Capture Timer value to CC[4] register |
| TASKS_CAPTURE[5] | 0x054 | Capture Timer value to CC[5] register |
| EVENTS_COMPARE[0] | 0x140 | Compare event on CC[0] match |
| EVENTS_COMPARE[1] | 0x144 | Compare event on CC[1] match |
| EVENTS_COMPARE[2] | 0x148 | Compare event on CC[2] match |
| EVENTS_COMPARE[3] | 0x14C | Compare event on CC[3] match |
| EVENTS_COMPARE[4] | 0x150 | Compare event on CC[4] match |
| EVENTS_COMPARE[5] | 0x154 | Compare event on CC[5] match |



Example PPI use case

- Automatic high-speed ADC sampling
- Software configures and sleeps
 - ADC (buffer and enable)
 - Timer (prescaler, compare value, short from compare to clear, and start)
- PPI: When Timer fires (EVENTS_COMPARE[0]),
 - Sample ADC (TASKS_SAMPLE)
- PPI: When ADC buffer full (EVENTS_END),
 - Stop Timer (TASKS_STOP)
 - Fork: wake processor (via software interrupt from EGU)